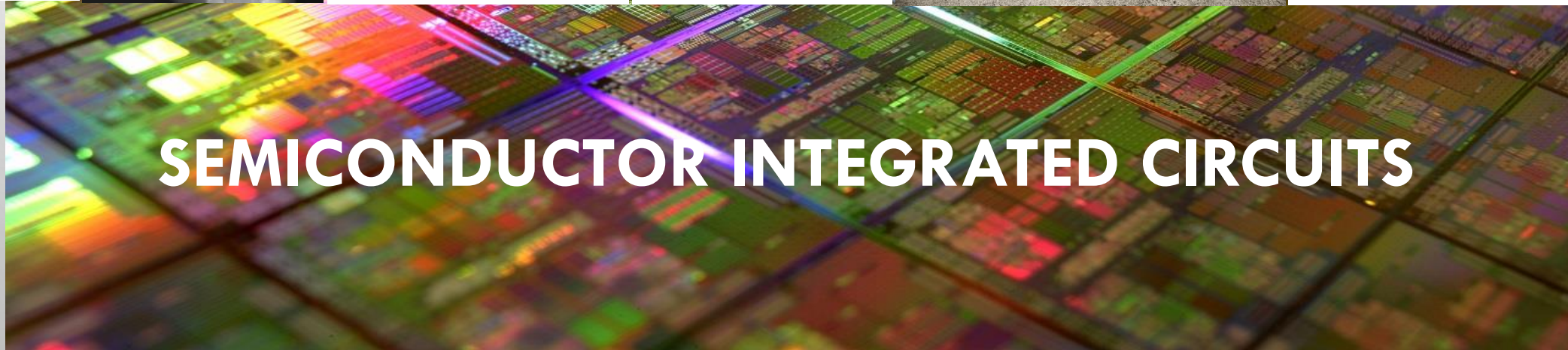
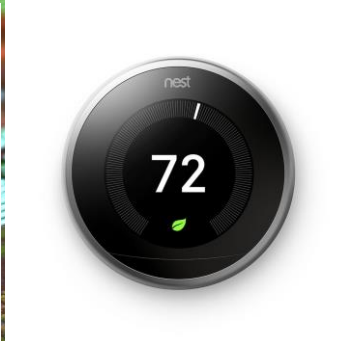


VERSATILITY OF A
CONDENSATION GROWTH TUBE
FOR AEROSOL AND HYDROSOL
COLLECTION USING A

nanoSpotLight™

PAT KEADY, President, Aerosol Devices Inc





SEMICONDUCTOR INTEGRATED CIRCUITS

SEMICONDUCTOR ULTRAPURE WATER (UPW)

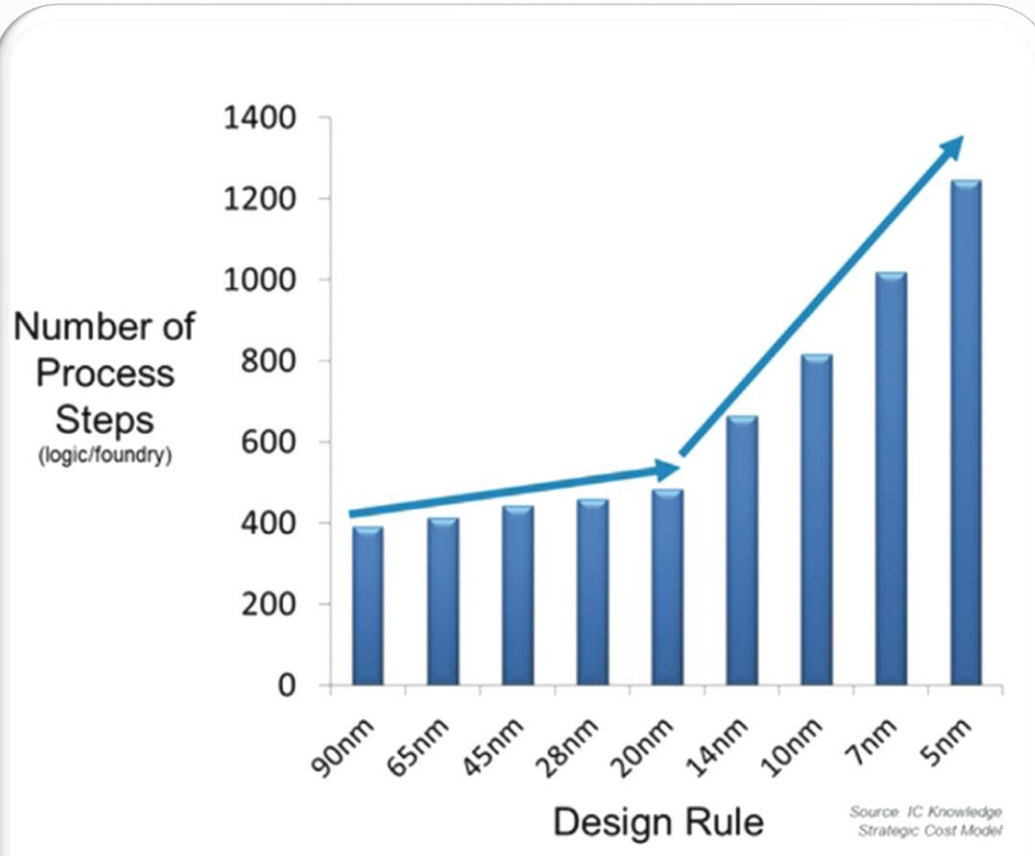


- Highest grade of water lacking contaminants: microorganisms, dissolved and particulate matter, minerals, organic or inorganic chemicals
- Used extensively for rinsing, diluting chemicals, other processes
- Purified to the level at or below our metrology detection limits – or is it?

NODE SIZE

- [10 μm](#) – 1971
- [6 μm](#) – 1974
- [3 μm](#) – 1977
- [1.5 μm](#) – 1982
- [1 μm](#) – 1985
- [800 nm](#) – 1989
- [600 nm](#) – 1994
- [350 nm](#) – 1995
- [250 nm](#) – 1997
- [180 nm](#) – 1999
- [130 nm](#) – 2001
- [90 nm](#) – 2004
- [65 nm](#) – 2006
- [45 nm](#) – 2008
- [32 nm](#) – 2010
- [22 nm](#) – 2012
- [14 nm](#) – 2014
- [10 nm](#) – 2017
- [7 nm](#) – ~2018
- [5 nm](#) – ~2020

Limit of Moore's Law?



MOORE'S LAW

“Transistor density on integrated circuits doubles about every two years.”

SHRINKING NODES
means
INCREASING PROCESS
STEPS

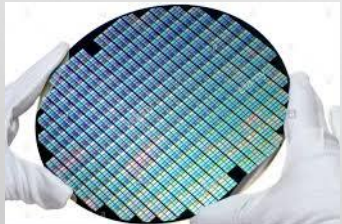
and SHRINKING
KILLER PARTICLE SIZE

UPW and AIR particle
contamination potential
multiplies

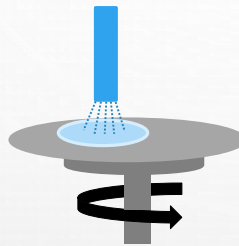
SEMICONDUCTOR PROCESSES ULTRAPURE WATER (UPW)

PROCESS STEPS

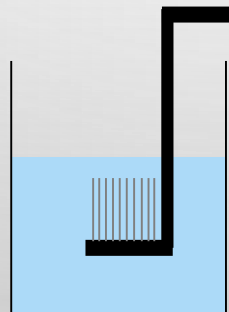
- FRONT END
- BACK END
- TEST
- PACKAGING



- Wafer processing
- Wet cleans
- Photolithography
- Ion implantation
- Dry etching
- Wet etching
- Plasma ashing
- Thermal treatments
- Rapid thermal anneal
- Furnace anneals
- Thermal oxidation
- Chemical vapor deposition (CVD)
- Physical vapor deposition (PVD)
- Molecular beam epitaxy (MBE)
- Electrochemical Deposition (ECD)
- Chemical-mechanical planarization (CMP)
- Wafer testing
- Wafer backgrinding
- Die preparation
- Wafer mounting
- Die cutting
- IC packaging
- Die attachment
- IC Bonding
- Wire bonding
- Flip chip
- Tab bonding
- IC encapsulation
- Baking
- Plating



UPW RINSE



UPW SUPPLY

RECLAIM

RECYCLE

UPW WASTE

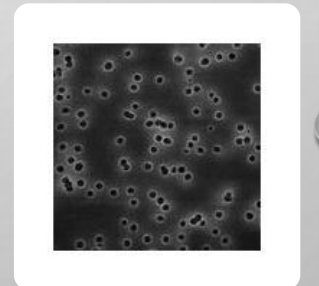


TREATMENT / WASTE



ON-LINE
PARTICLE
MONITOR

SAMPLING/
OFF-LINE
ANALYSIS



ON-LINE UPW PARTICLE MONITORING TECHNOLOGY HAS HIT THE WALL

Optical particle counter (OPC) –
3% detection sensitivity at 20 nm

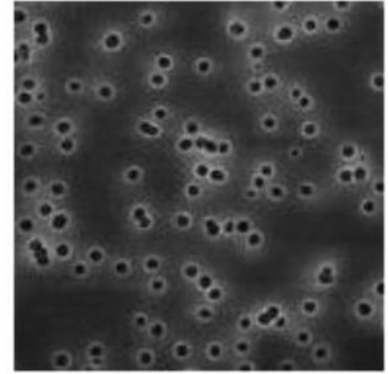
**BUT, industry needs PARTICLE detection
down to 7 nm (or lower)!**



PARTICLE SAMPLING – OFF-LINE SEM/EDX ANALYSIS

MEMBRANE FILTRATION

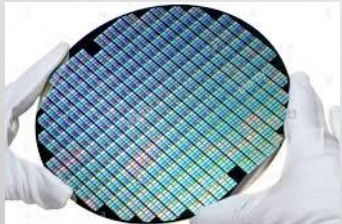
- ✓ Slow
- ✓ Hard to find the particles
- ✓ Inability to retain smaller killer particles



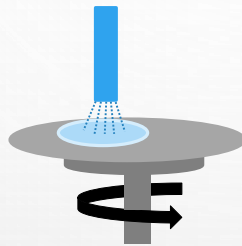
SEMICONDUCTOR PROCESSES ULTRAPURE WATER (UPW)

PROCESS STEPS

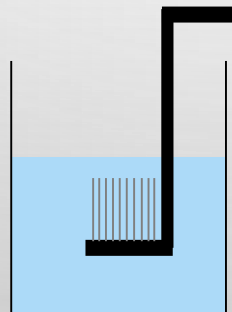
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UPW RINSE



UPW SUPPLY

RECLAIM

RECYCLE

UPW WASTE

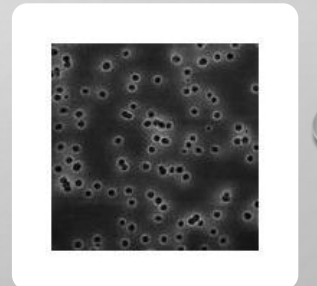


TREATMENT / WASTE



ON-LINE
PARTICLE
MONITOR

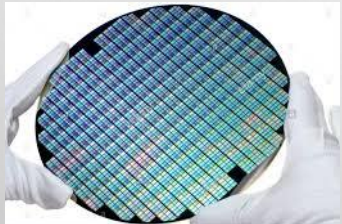
SAMPLING/
OFF-LINE
ANALYSIS



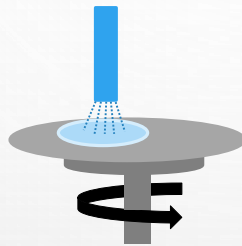
SEMICONDUCTOR PROCESSES ULTRAPURE WATER (UPW)

PROCESS STEPS

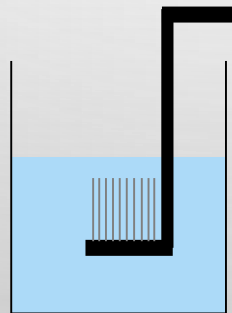
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UPW RINSE



UPW SUPPLY

RECLAIM

RECYCLE

UPW WASTE



TREATMENT / WASTE



STPC
PARTICLE
MONITOR

nanoSpotLight /
OFF-LINE
ANALYSIS

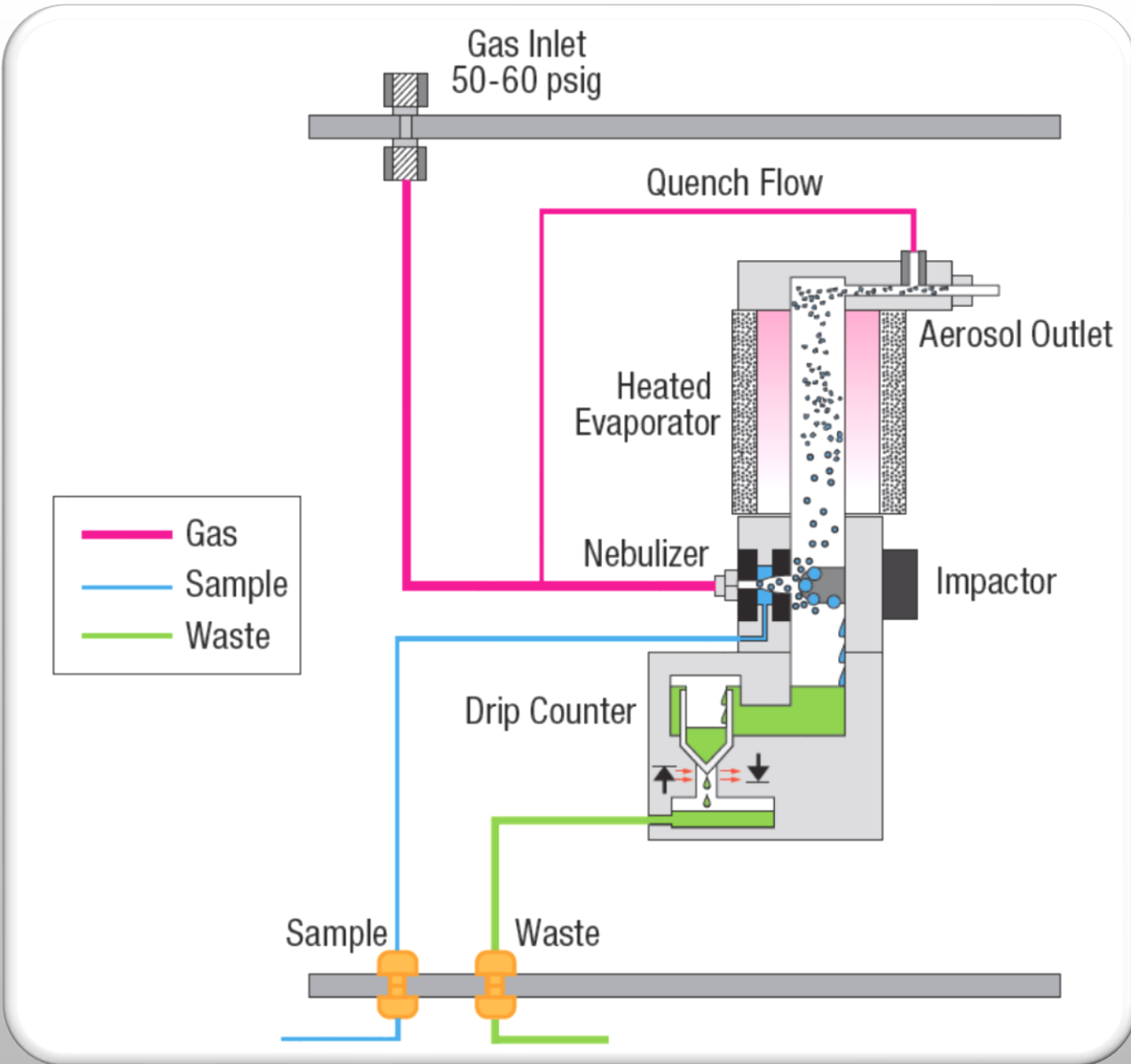


A NEW APPROACH *from Aerosol Science*

nanoSpotLight UPW Particle Sampler

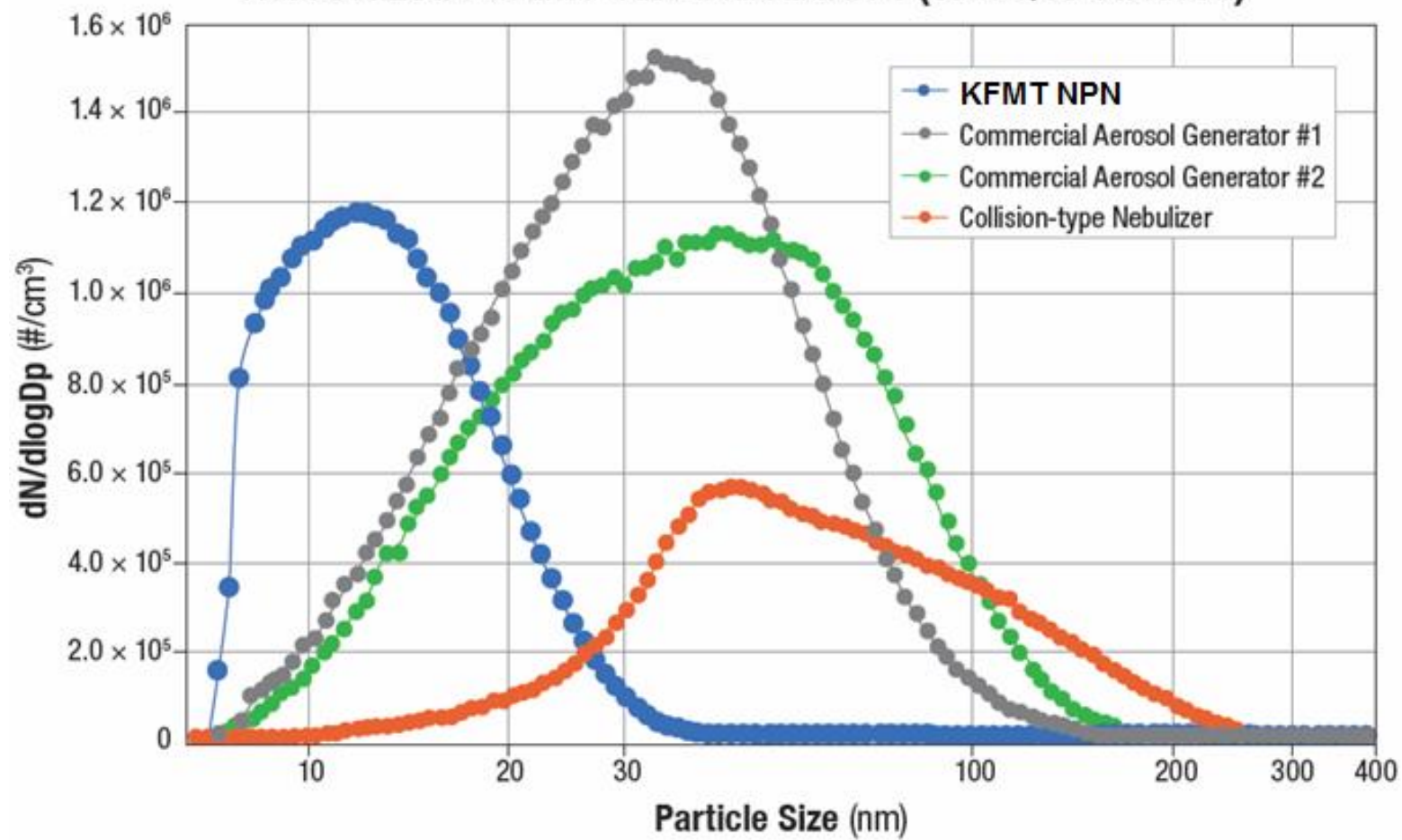


- Combines UPW nebulization with condensation growth aerosol particle collection
- FOCUSED AEROSOL DEPOSITION on a test silicon wafer or substrate on SEM pin
- Off-line analysis using SEM/EDX for physical, chemical, and biological characterization
 - ✓ Count
 - ✓ Size
 - ✓ Shape
 - ✓ Chemical composition



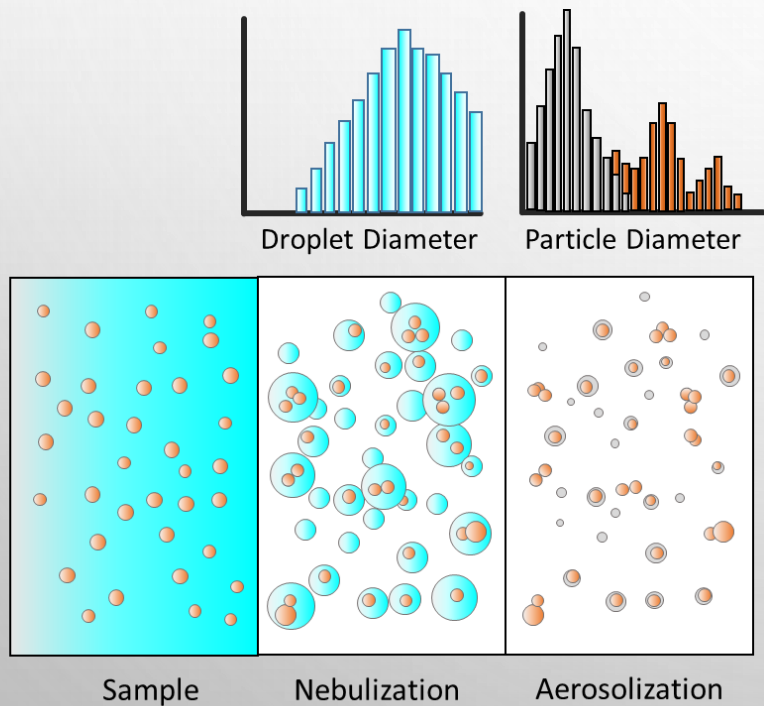
NANOPARTICLE NEBULIZER

Aerosolized Particle Size Distribution (0.001%v Sucrose)

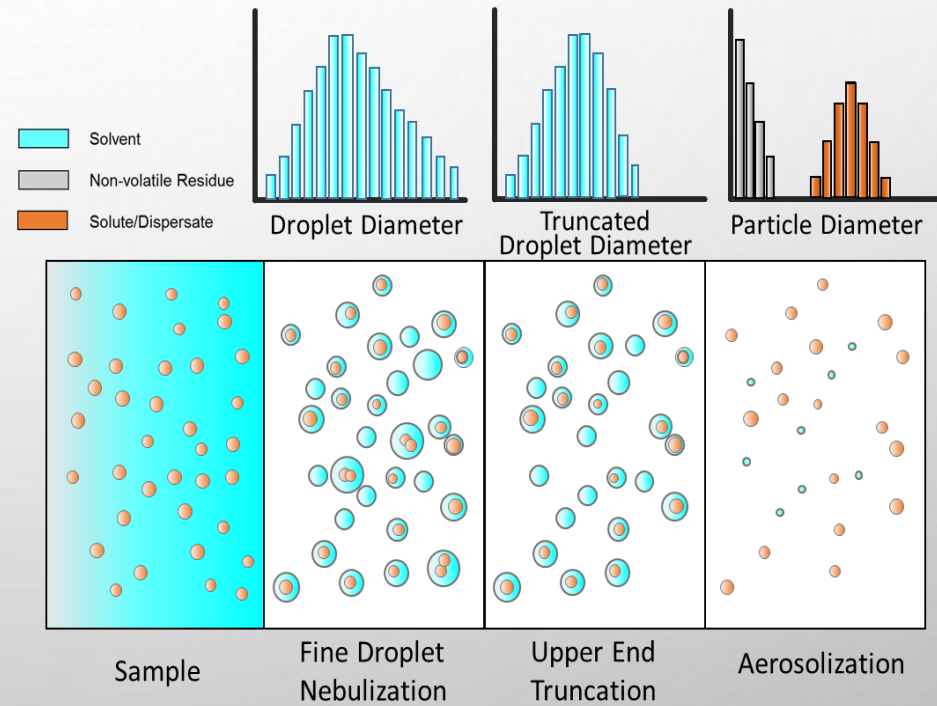


PARTICLES SEPARATED FROM DISSOLVED NON-VOLATILE RESIDUE

Traditional Nebulizer

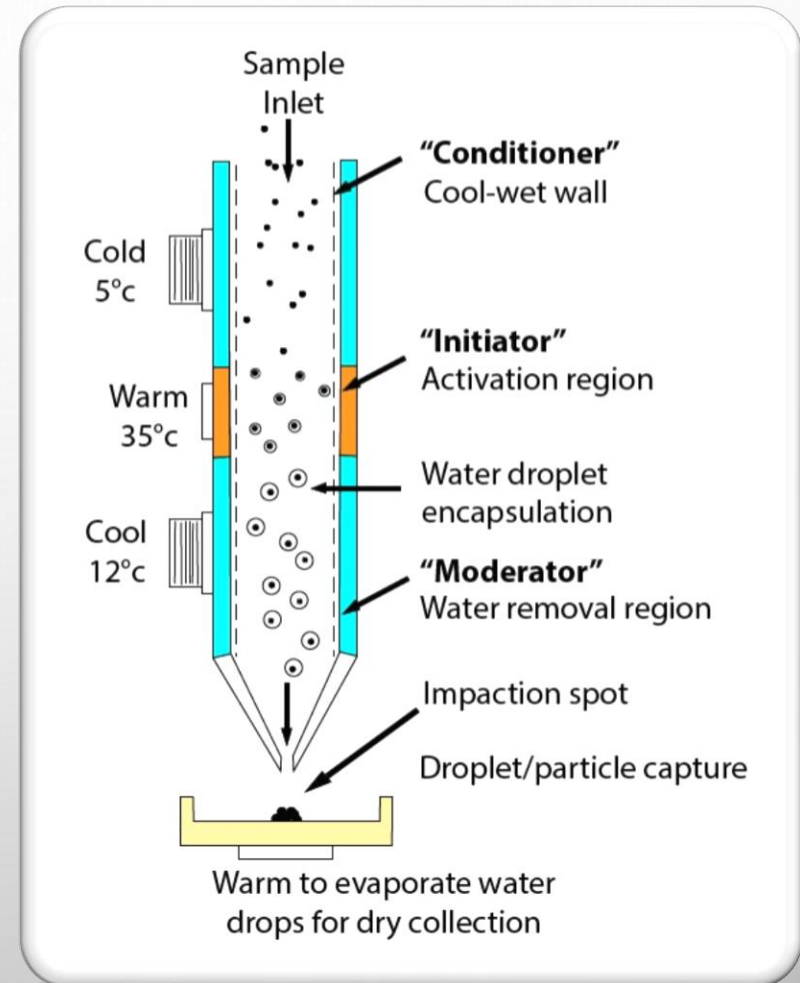


NanoParticle Nebulizer

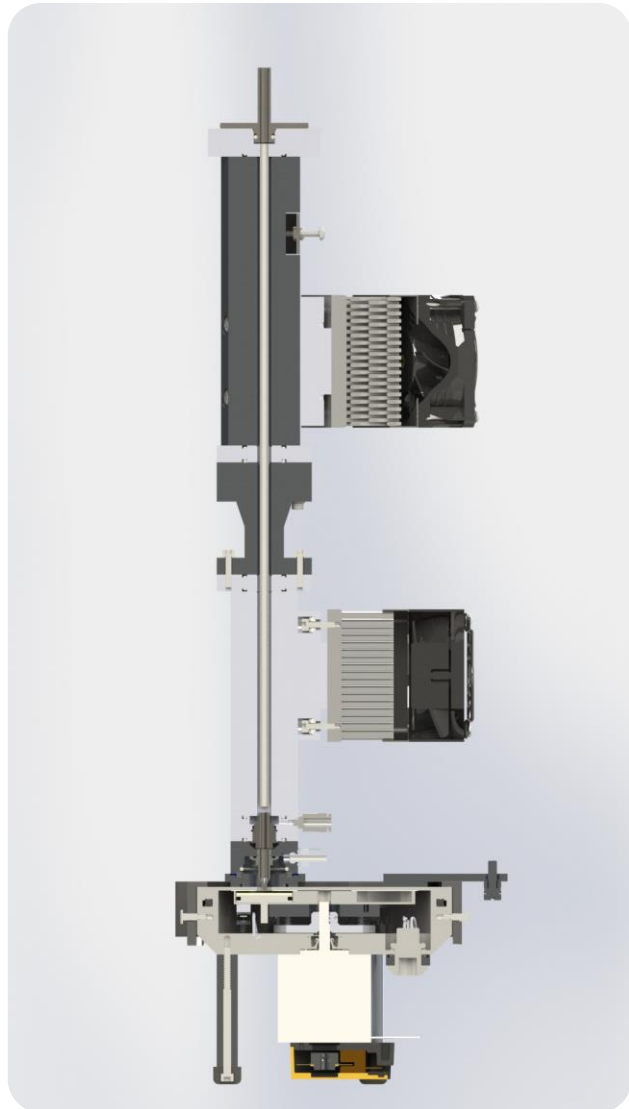
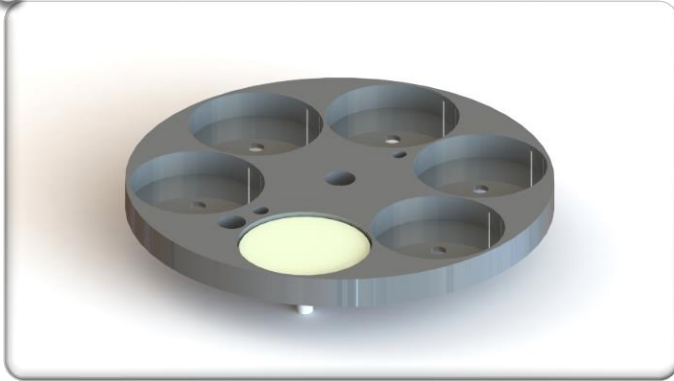


CONDENSATION GROWTH TUBE COLLECTION

- Rapid sampling in 24 hours – or as little as 10 minutes for a contamination event
- Concentrated particle sample – 1 mm “spot” deposit centered on the SEM collection plate
- High-efficiency collection $> 95\%$ for particles down to 5nm
- Time-resolved samples on a sample platen holding six SEM stubs – add sample substrate of choice
- Collects ALL particles $> 10\text{nm}$ independent of composition

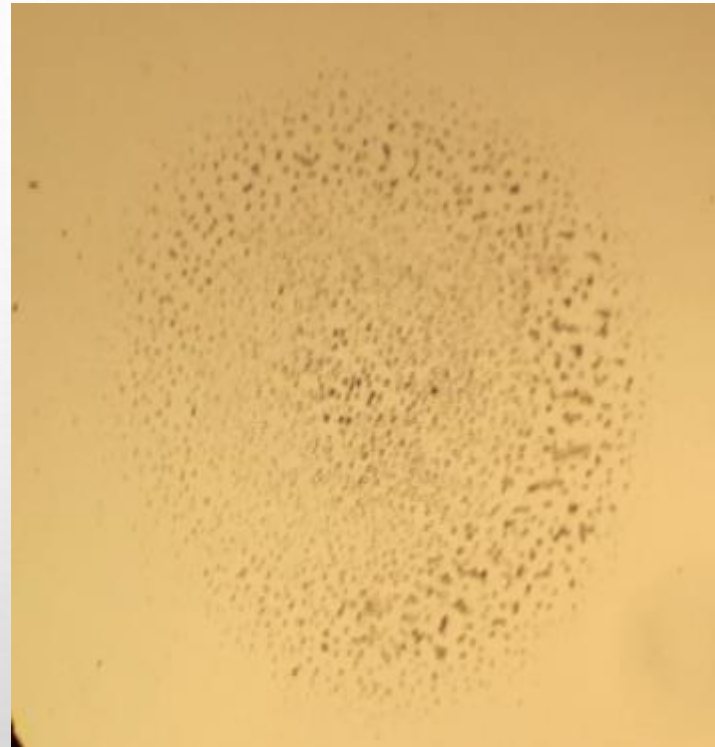


SEM STUB PLATEN IN
SEQUENTIAL
COLLECTOR MODULE



FOCUSED AEROSOL “SPOT” DEPOSIT ON SILICA WAFER

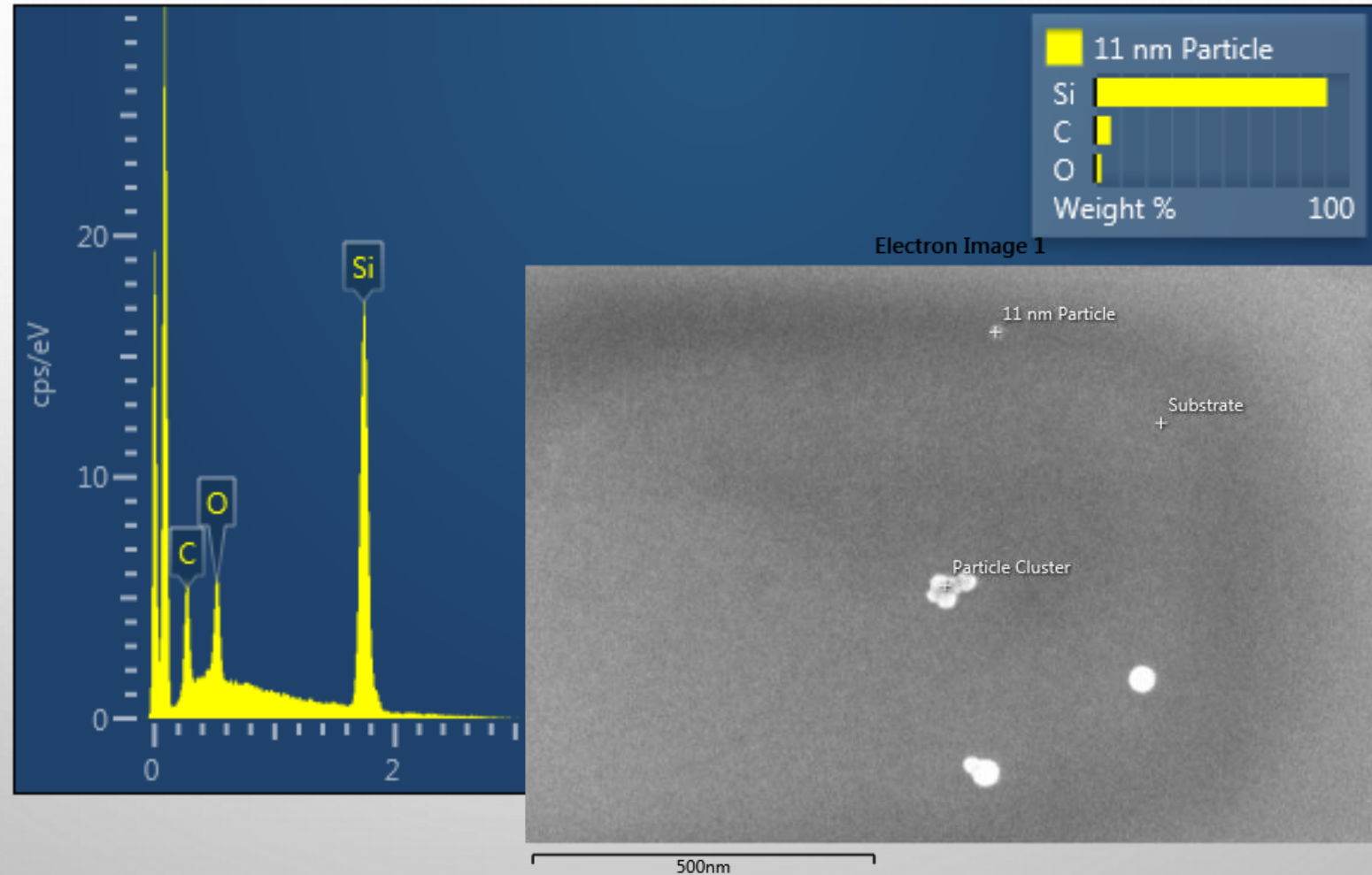
Spot pattern at
50 X magnification



← 1mm →

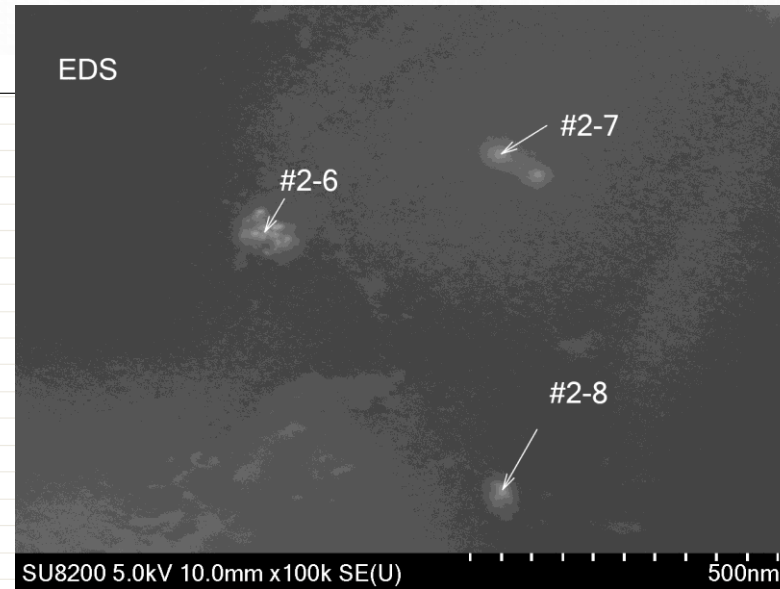
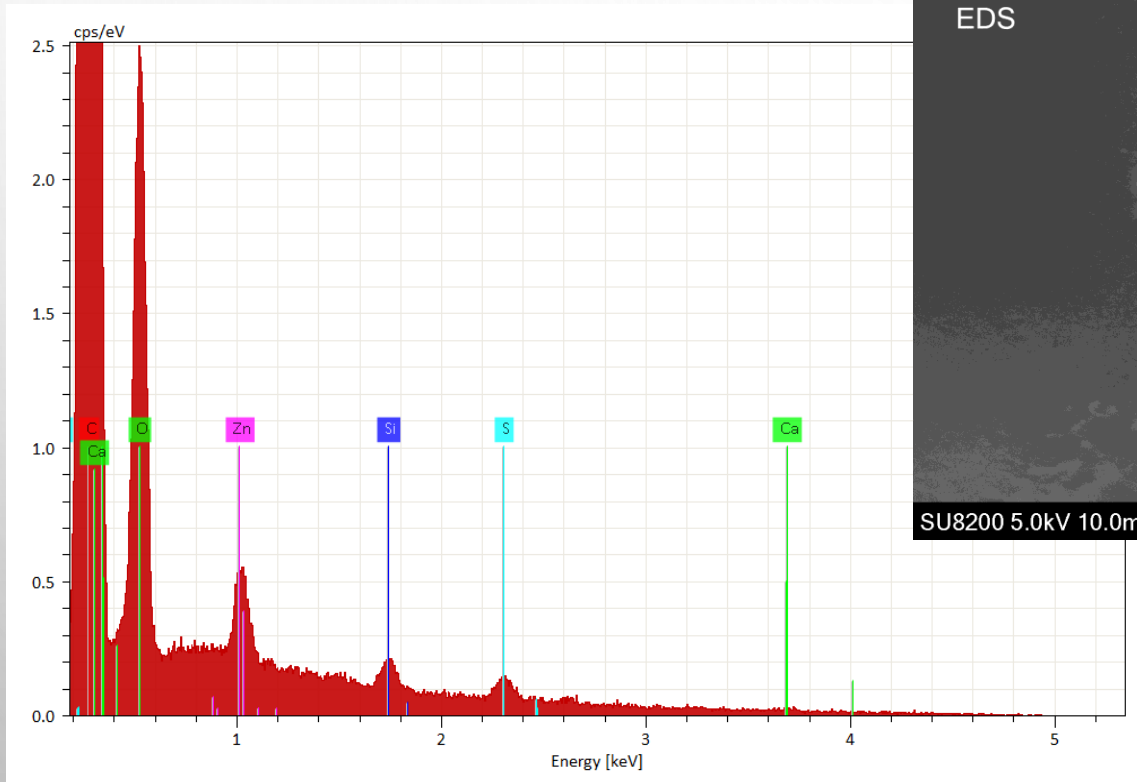
SEM/EDX - SILICA PARTICLES INJECTED INTO UPW

10nm colloidal silica
3 hr collection
Silica wafer substrate



SEM/EDX ANALYSIS ON A CARBON SUBSTRATE

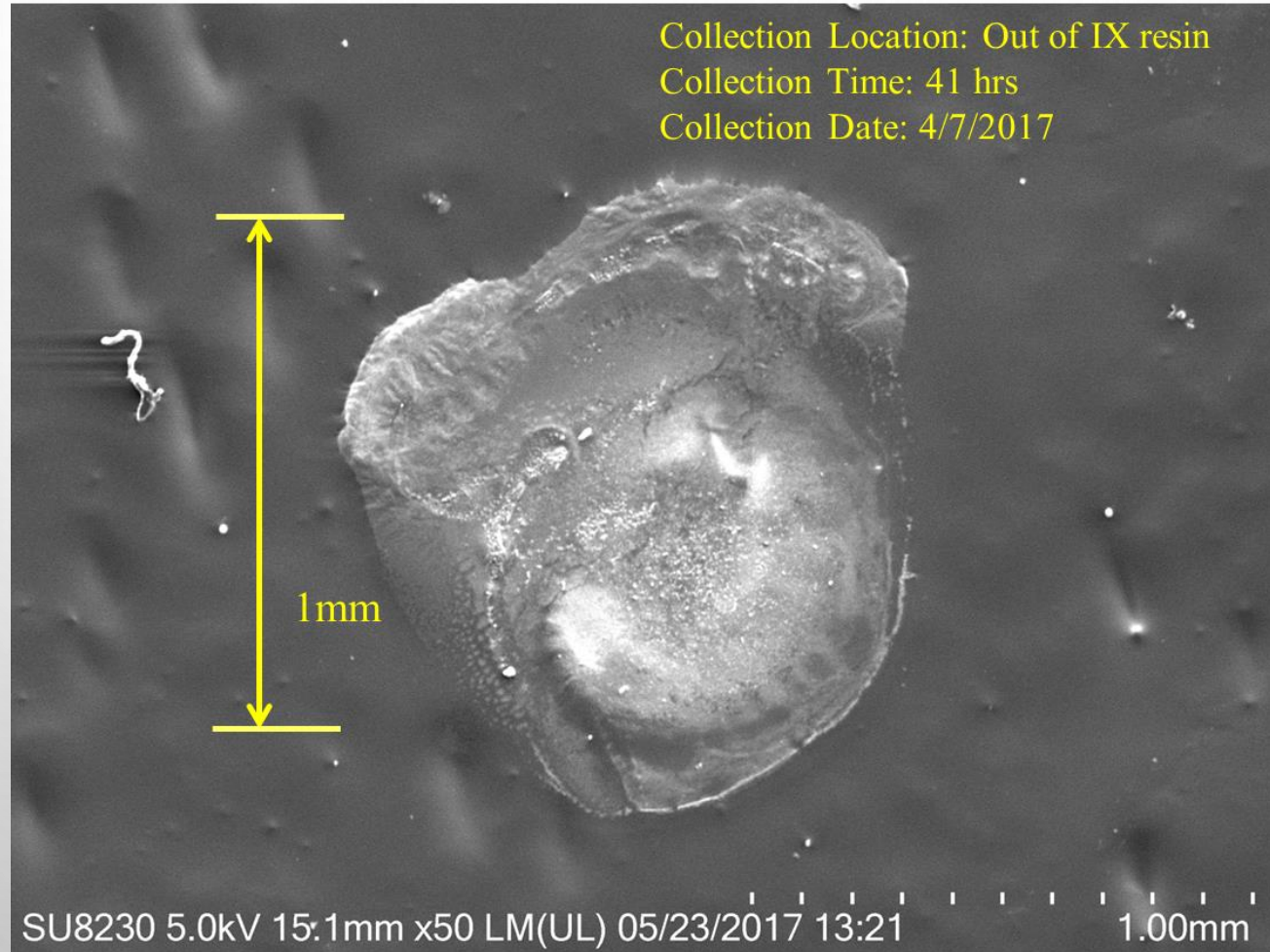
2-8



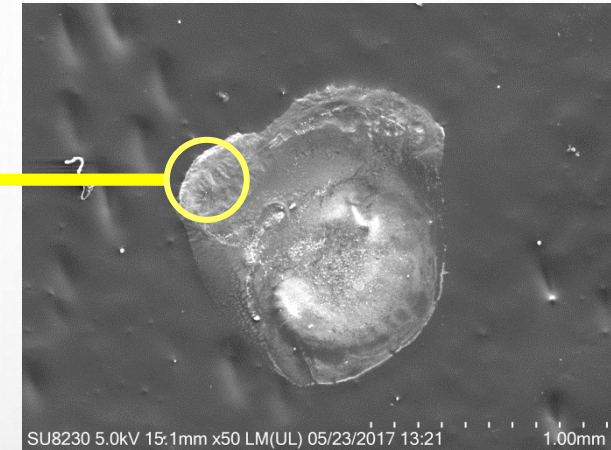
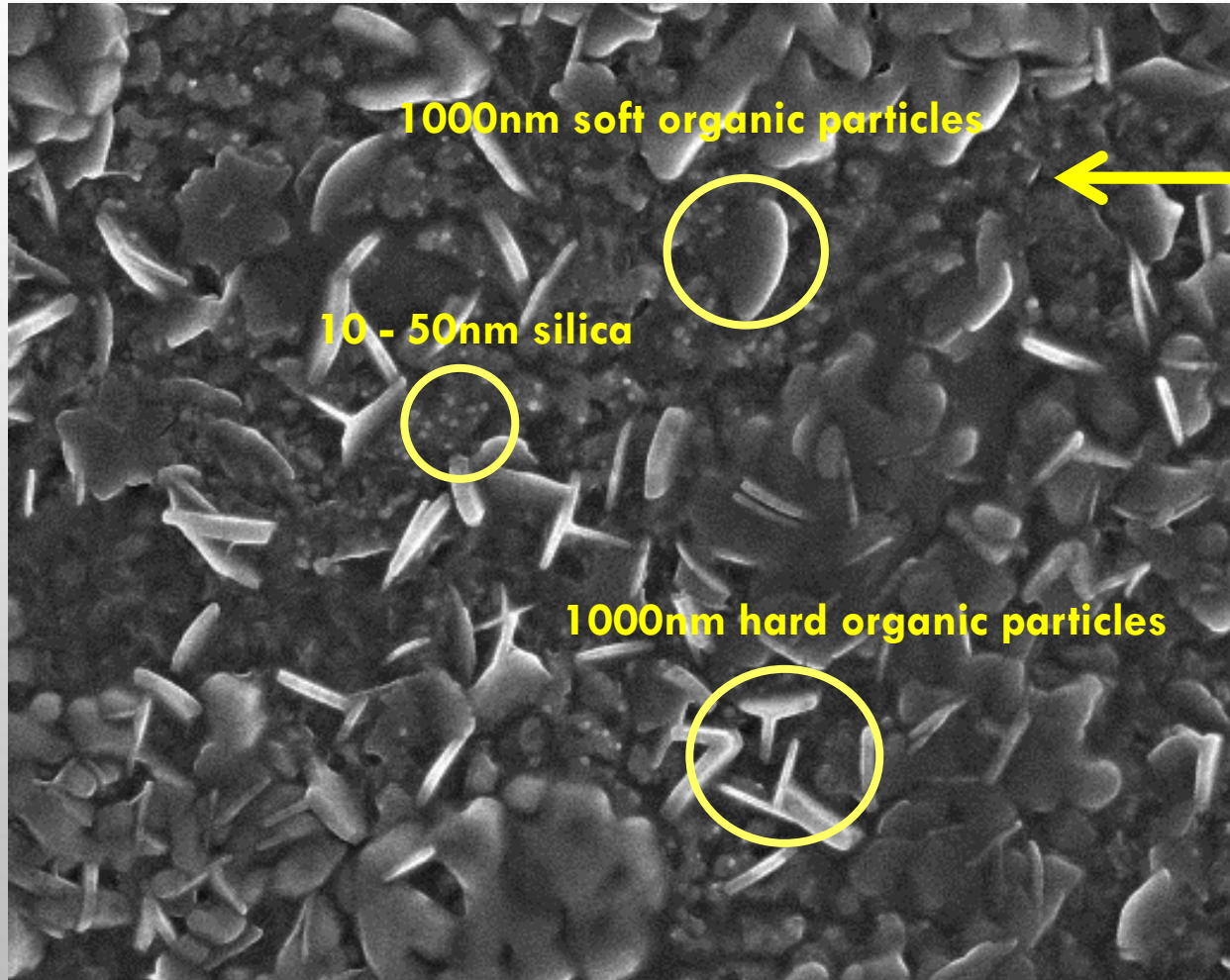
Real UPW sample
24 hr collection time

Elements detected:
Carbon
Oxygen
Calcium
Zinc
Silicon
Sulphur

FOCUSED AEROSOL DEPOSIT ON COPPER SUBSTRATE



SEM/EDX AFTER CONTAMINATION EVENT



Elements Detected:

- Carbon
- Oxygen
- Silicon
- Sulphur
- Zinc
- Magnesium

NEXT STEPS

Compare NanoSpotLight with STPC and laser particle counter on UPW system, round 2

Further testing of substrate materials for best SEM analysis to “see” organics, metals, silica

Sample platen pre-installed with 6 silica wafers on SEM stubs – assembled in a clean room by CT Associates Inc

Tighten focus of the droplet deposition to reduce deposition spot size

UPW audit and analysis services by CT Associates

NanoSpotLight UPW system available from KanomaxFMT
SEM stub sequential collector available for Spot Sampler from Aerosol Devices



CT Associates
INCORPORATED



THE NEED FOR UPW NANOPARTICLE MONITORING IS CLEAR

**Largest & Most Influential
Semiconductor Companies:**

Intel

Samsung

TSMC

Global Foundries

With special thanks to:
David Blackford,
Derek Oberreit, Siqin He
and Gary Anderson,
KanomaxFMT;
Gary Van Schooneveld,
CT Associates;
Slava Libmann,
FDT Solutions LLC

THANK YOU FOR
YOUR ATTENTION



PAT KEADY

pkeady@aerosoldevices.com